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- **EPIC™** (Enhanced-Performance Implanted **CMOS) Process**
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015
- **Package Options Include Plastic** Small-Outline (D), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

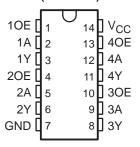
description

The 'AHCT126 devices are quadruple bus buffer gates featuring independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (OE) input is low. When OE is high, the respective gate passes the data from the A input to its Y output.

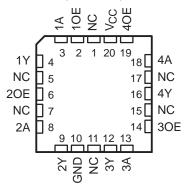
To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SN54AHCT126 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT126 is characterized for operation from -40°C to 85°C.

SN54AHCT126...J OR W PACKAGE SN74AHCT126 . . . D, DB, DGV, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT126...FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE (each buffer)

INP	JTS	OUTPUT
OE	Α	Υ
Н	Н	Н
Н	L	L
L	Χ	Z



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

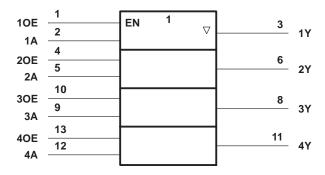
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SN54AHCT126, SN74AHCT126 QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

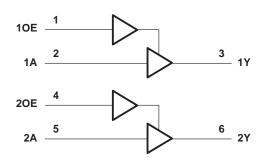
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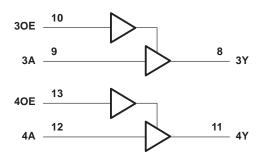
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

logic diagram (positive logic)





Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Note 1)		. $-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}(V_I < 0)$		–20 mA
Output clamp current, IOK (VO < 0 or VO > VCO	;)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ _{JA} (see Note 2):	D package	86°C/W
	DB package	96°C/W
	DGV package	127°C/W
	N package	80°C/W
	PW package	113°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.



recommended operating conditions (see Note 3)

		SN54AHCT126		SN74AH	UNIT	
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	VCC	0	VCC	V
Іон	High-level output current		-8		-8	mA
l _{OL}	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
TA	Operating free-air temperature	- 55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T _A = 25°C			SN54AHCT126		SN74AHCT126		UNIT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
W	I _{OH} = -50 μA	4.5.1/	4.4	4.5		4.4		4.4		V
VOH	I _{OH} = -8 mA	4.5 V 3.94				3.8		3.8		
\/o:	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
VOL	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44	V
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20		20	μΑ
∆l _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C _i	V _I = V _{CC} or GND	5 V		4	10				10	pF
Co	VO = VCC or GND	5 V		15						pF

 $^{^{*}}$ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.



[†] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

SN54AHCT126, SN74AHCT126 **QUADRUPLE BUS BUFFER GATES** WITH 3-STATE OUTPUTS

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	λ = 25°C	;	SN54AH	CT126	SN74AH	CT126	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	A	Y	C 15 pF		3.8*	5.5*	1*	6.5*	1	6.5	ns
t _{PHL}		'	C _L = 15 pF		3.8*	5.5*	1*	6.5*	1	6.5	115
^t PZH	OE Y	Y	C _L = 15 pF		3.6*	5.1*	1*	6*	1	6	ns
t _{PZL}		ī	CL = 15 pr		3.6*	5.1*	1*	6*	1	6	115
t _{PHZ}	OE	Y	C _L = 15 pF		4.6*	6.8*	1*	8*	1	8	ns
t _{PLZ}	OL	ī	1 CL = 15 pr		4.6*	6.8*	1*	8*	1	8	118
t _{PLH}	Δ	Y	C: 50 pF		5.3	7.5	1	8.5	1	8.5	
t _{PHL}	Α	Ť	C _L = 50 pF		5.3	7.5	1	8.5	1	8.5	ns
^t PZH	0.5	OE Y	C: 50 pF		5.1	7.1	1	8	1	8	
t _{PZL}	OE		OE Y	C _L = 50 pF		5.1	7.1	1	8	1	8
t _{PHZ}	OE	Y	C. = 50 pE		6.1	8.8	1	10	1	10	ns
t _{PLZ}		ſ	$C_L = 50 \text{ pF}$		6.1	8.8	1	10	1	10	115
t _{sk(o)}			C _L = 50 pF			1**				1	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER -		SN74AHCT126		
			MAX	UNIT	
VOL(P)	Quiet output, maximum dynamic V _{OL}		0.8	V	
V _{OL} (V)	Quiet output, minimum dynamic V _{OL}		-0.8	V	
V _{OH(V)}	Quiet output, minimum dynamic VOH	4.4		V	
VIH(D)	High-level dynamic input voltage	2		V	
V _{IL(D)}	Low-level dynamic input voltage		0.8	V	

NOTE 4: Characteristics are for surface-mount packages only.

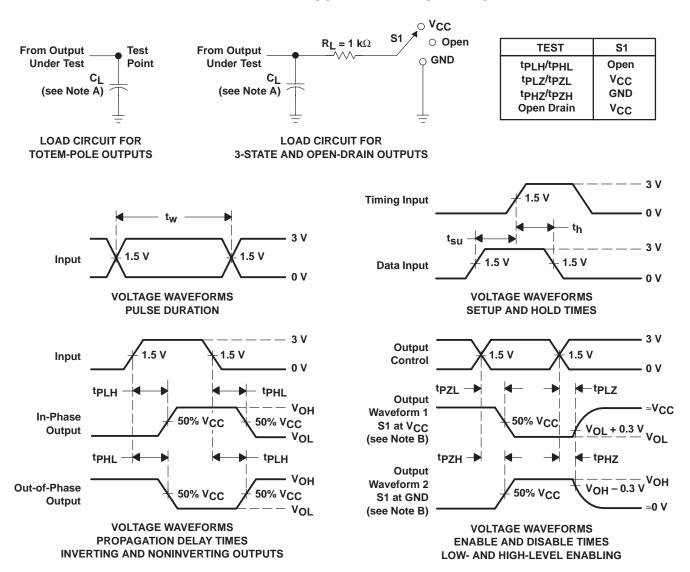
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load, f = 1 MHz	14	pF



^{**} On products compliant to MIL-PRF-38535, this parameter does not apply.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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